Diode Semiconductor Device - Page 1 of 1



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Ir	nclosure Material:
G	Blass and metal
C	Overall Length:
0	.030 inches
Т	erminal Length:
1	.000 inches
C	Overall Diameter:
0	.450 inches
N	Iounting Method:
Т	erminal
F	eatures Provided:
F	lermetically sealed case
S	emiconductor Material:
S	ilicon
۷	oltage Rating In Volts Per Characteristic:
-4	400.0 reverse voltage, peak
С	Current Rating Per Characteristic:
3	.00 amperes source cutoff current preset
N	Iaximum Operating Tempurature Per Measurement Point:
1	50.0 degrees celsius junction
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	shelf Life:
Ν	l/a
U	Init Of Measure:
D	emilitarization:
Ν	lo
F	iig:
А	.110a0